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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, I²C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	79
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 28x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5604bavll6r

Table 2. MPC5604B/C device comparison[1]

Feature	Device										
	SPC560B 40L1	**SPC560B 40L3**	**SPC560B 40L5**	**SPC560C 40L1**	**SPC560C 40L3**	**SPC560B 50L1**	**SPC560B 50L3**	**SPC560B 50L5**	**SPC560C 50L1**	**SPC560C 50L3**	**SPC560B 50B2**
CPU	e200z0h										
Execution speed[2]	Static – up to 64 MHz										
Code Flash	256 KB					512 KB					
Data Flash	64 KB (4 × 16 KB)										
RAM	24 KB			32 KB		32 KB			48 KB		
MPU	8-entry										
ADC (10-bit)	12 ch	28 ch	36 ch	8 ch	28 ch	12 ch	28 ch	36 ch	8 ch	28 ch	36 ch
CTU	Yes										
Total timer I/O[3] eMIOS	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit
• PWM + MC + IC/OC[4]	2 ch	5 ch	10 ch	2 ch	5 ch	2 ch	5 ch	10 ch	2 ch	5 ch	10 ch
• PWM + IC/OC[4]	10 ch	20 ch	40 ch	10 ch	20 ch	10 ch	20 ch	40 ch	10 ch	20 ch	40 ch
• IC/OC[4]	—	3 ch	6 ch	—	3 ch	—	3 ch	6 ch	—	3 ch	6 ch
SCI (LINFlex)	3[5]			4							
SPI (DSPI)	2	3		2	3	2	3		2	3	
CAN (FlexCAN)	2[6]			5	6	3[7]			5	6	
I^2C	1										
32 kHz oscillator	Yes										
GPIO[8]	45	79	123	45	79	45	79	123	45	79	123
Debug	JTAG										Nexus2+
Package	LQFP64[9]	LQFP100	LQFP144	LQFP64[9]	LQFP100	LQFP64[9]	LQFP100	LQFP144	LQFP64[9]	LQFP100	LBGA208[10]

1 Feature set dependent on selected peripheral multiplexing—table shows example implementation

2 Based on 125 °C ambient operating temperature

3 See the eMIOS section of the device reference manual for information on the channel configuration and functions.

4 IC – Input Capture; OC – Output Compare; PWM – Pulse Width Modulation; MC – Modulus counter

5 SCI0, SCI1 and SCI2 are available. SCI3 is not available.

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PB[3]	PCR[19]	AF0 AF1 AF2 AF3 — —	GPIO[19] — SCL — WKPU[11][4] LIN0RX	SIUL — I2C_0 — WKPU LINFlex_0	I/O — I/O — I I	S	Tristate	1	1	1	1	C3
PB[4]	PCR[20]	AF0 AF1 AF2 AF3 —	GPIO[20] — — — GPI[0]	SIUL — — — ADC	I — — — I	I	Tristate	32	32	50	72	T16
PB[5]	PCR[21]	AF0 AF1 AF2 AF3 —	GPIO[21] — — — GPI[1]	SIUL — — — ADC	I — — — I	I	Tristate	35	—	53	75	R16
PB[6]	PCR[22]	AF0 AF1 AF2 AF3 —	GPIO[22] — — — GPI[2]	SIUL — — — ADC	I — — — I	I	Tristate	36	—	54	76	P15
PB[7]	PCR[23]	AF0 AF1 AF2 AF3 —	GPIO[23] — — — GPI[3]	SIUL — — — ADC	I — — — I	I	Tristate	37	35	55	77	P16
PB[8]	PCR[24]	AF0 AF1 AF2 AF3 — —	GPIO[24] — — — ANS[0] OSC32K_XTAL[7]	SIUL — — — ADC SXOSC	I — — — I I/O	I	Tristate	30	30	39	53	R9
PB[9]	PCR[25]	AF0 AF1 AF2 AF3 — —	GPIO[25] — — — ANS[1] OSC32K_EXTAL[7]	SIUL — — — ADC SXOSC	I — — — I I/O	I	Tristate	29	29	38	52	T9

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PB[10]	PCR[26]	AF0 AF1 AF2 AF3 — —	GPIO[26] — — — ANS[2] WKPU[8][4]	SIUL — — — ADC WKPU	I/O — — — I I	J	Tristate	31	31	40	54	P9
PB[11][8]	PCR[27]	AF0 AF1 AF2 AF3 —	GPIO[27] E0UC[3] — CS0_0 ANS[3]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — I/O I	J	Tristate	38	36	59	81	N13
PB[12]	PCR[28]	AF0 AF1 AF2 AF3 —	GPIO[28] E0UC[4] — CS1_0 ANX[0]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	39	—	61	83	M16
PB[13]	PCR[29]	AF0 AF1 AF2 AF3 —	GPIO[29] E0UC[5] — CS2_0 ANX[1]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	40	—	63	85	M13
PB[14]	PCR[30]	AF0 AF1 AF2 AF3 —	GPIO[30] E0UC[6] — CS3_0 ANX[2]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	41	37	65	87	L16
PB[15]	PCR[31]	AF0 AF1 AF2 AF3 —	GPIO[31] E0UC[7] — CS4_0 ANX[3]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	42	38	67	89	L13
PC[0][9]	PCR[32]	AF0 AF1 AF2 AF3	GPIO[32] — TDI —	SIUL — JTAGC —	I/O — I —	M	Input, weak pull-up	59	59	87	126	A8
PC[1][9]	PCR[33]	AF0 AF1 AF2 AF3	GPIO[33] — TDO[10] —	SIUL — JTAGC —	I/O — O —	M	Tristate	54	54	82	121	C9

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PD[1]	PCR[49]	AF0 AF1 AF2 AF3 —	GPIO[49] — — — GPI[5]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	42	64	T12
PD[2]	PCR[50]	AF0 AF1 AF2 AF3 —	GPIO[50] — — — GPI[6]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	43	65	R12
PD[3]	PCR[51]	AF0 AF1 AF2 AF3 —	GPIO[51] — — — GPI[7]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	44	66	P13
PD[4]	PCR[52]	AF0 AF1 AF2 AF3 —	GPIO[52] — — — GPI[8]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	45	67	R13
PD[5]	PCR[53]	AF0 AF1 AF2 AF3 —	GPIO[53] — — — GPI[9]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	46	68	T13
PD[6]	PCR[54]	AF0 AF1 AF2 AF3 —	GPIO[54] — — — GPI[10]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	47	69	T14
PD[7]	PCR[55]	AF0 AF1 AF2 AF3 —	GPIO[55] — — — GPI[11]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	48	70	R14
PD[8]	PCR[56]	AF0 AF1 AF2 AF3 —	GPIO[56] — — — GPI[12]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	49	71	T15

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PG[11]	PCR[107]	AF0 AF1 AF2 AF3	GPIO[107] E0UC[25] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	—	115	B12
PG[12]	PCR[108]	AF0 AF1 AF2 AF3	GPIO[108] E0UC[26] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	—	92	K14
PG[13]	PCR[109]	AF0 AF1 AF2 AF3	GPIO[109] E0UC[27] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	—	91	K16
PG[14]	PCR[110]	AF0 AF1 AF2 AF3	GPIO[110] E1UC[0] — —	SIUL eMIOS_1 — —	I/O I/O — —	S	Tristate	—	—	—	110	B14
PG[15]	PCR[111]	AF0 AF1 AF2 AF3	GPIO[111] E1UC[1] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	111	B13
PH[0]	PCR[112]	AF0 AF1 AF2 AF3 —	GPIO[112] E1UC[2] — — SIN1	SIUL eMIOS_1 — — DSPI_1	I/O I/O — — I	M	Tristate	—	—	—	93	F13
PH[1]	PCR[113]	AF0 AF1 AF2 AF3	GPIO[113] E1UC[3] SOUT1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O O —	M	Tristate	—	—	—	94	F14
PH[2]	PCR[114]	AF0 AF1 AF2 AF3	GPIO[114] E1UC[4] SCK_1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O I/O —	M	Tristate	—	—	—	95	F16
PH[3]	PCR[115]	AF0 AF1 AF2 AF3	GPIO[115] E1UC[5] CS0_1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O I/O —	M	Tristate	—	—	—	96	F15

[7] Value of PCR.IBE bit must be 0

[8] Be aware that this pad is used on the MPC5607B 100-pin and 144-pin to provide VDD_HV_ADC and VSS_HV_ADC1. Therefore, you should be careful in ensuring compatibility between MPC5604B/C and MPC5607B.

[9] Out of reset all the functional pins except PC[0:1] and PH[9:10] are available to the user as GPIO.
PC[0:1] are available as JTAG pins (TDI and TDO respectively).
PH[9:10] are available as JTAG pins (TCK and TMS respectively).
If the user configures these JTAG pins in GPIO mode the device is no longer compliant with IEEE 1149.1-2001.

[10] The TDO pad has been moved into the STANDBY domain in order to allow low-power debug handshaking in STANDBY mode. However, no pull-resistor is active on the TDO pad while in STANDBY mode. At this time the pad is configured as an input. When no debugger is connected the TDO pad is floating causing additional current consumption. To avoid the extra consumption TDO must be connected. An external pull-up resistor in the range of 47–100 kΩ should be added between the TDO pin and VDD_HV. Only in case the TDO pin is used as application pin and a pull-up cannot be used then a pull-down resistor with the same value should be used between TDO pin and GND instead.

[11] Available only on MPC560xC versions, MPC5603B 64 LQFP, MPC5604B 64 LQFP and MPC5604B 208 MAPBGA devices

[12] Not available on MPC5602B devices

[13] Not available in 100 LQFP package

[14] Available only on MPC5604B 208 MAPBGA devices

[15] Not available on MPC5603B 144-pin devices

3.7 Nexus 2+ pins

In the 208 MAPBGA package, eight additional debug pins are available (see Table 7).

Table 7. Nexus 2+ pin descriptions

Debug pin	Function	I/O direction	Pad type	Function after reset	Pin number		
					100 LQFP	144 LQFP	208 MAP BGA[1]
MCKO	Message clock out	O	F	—	—	—	T4
MDO0	Message data out 0	O	M	—	—	—	H15
MDO1	Message data out 1	O	M	—	—	—	H16
MDO2	Message data out 2	O	M	—	—	—	H14
MDO3	Message data out 3	O	M	—	—	—	H13
EVTI	Event in	I	M	Pull-up	—	—	K1
EVTO	Event out	O	M	—	—	—	L4
MSEO	Message start/end out	O	M	—	—	—	G16

[1] 208 MAPBGA available only as development package for Nexus2+

3.8 Electrical characteristics

3.9 Introduction

This section contains electrical characteristics of the device as well as temperature and power considerations.

[1] Default manufacturing value is ‘1’. Value can be programmed by customer in Shadow Flash.

3.11.2 NVUSRO[OSCILLATOR_MARGIN] field description

The fast external crystal oscillator consumption is dependent on the OSCILLATOR_MARGIN bit value. Table 10 shows how NVUSRO[OSCILLATOR_MARGIN] controls the device configuration.

Table 10. OSCILLATOR_MARGIN field description

Value[1]	Description
0	Low consumption configuration (4 MHz/8 MHz)
1	High margin configuration (4 MHz/16 MHz)

[1] Default manufacturing value is ‘1’. Value can be programmed by customer in Shadow Flash.

3.11.3 NVUSRO[WATCHDOG_EN] field description

The watchdog enable/disable configuration after reset is dependent on the WATCHDOG_EN bit value. Table 11 shows how NVUSRO[WATCHDOG_EN] controls the device configuration.

Table 11. WATCHDOG_EN field description

Value[1]	Description
0	Disable after reset
1	Enable after reset

[1] Default manufacturing value is ‘1’. Value can be programmed by customer in Shadow Flash.

3.12 Absolute maximum ratings

Table 12. Absolute maximum ratings

Symbol		Parameter	Conditions	Value		Unit
				Min	Max	
V_{SS}	SR	Digital ground on VSS_HV pins	—	0	0	V
V_{DD}	SR	Voltage on VDD_HV pins with respect to ground (V_{SS})	—	–0.3	6.0	V
V_{SS_LV}	SR	Voltage on VSS_LV (low voltage digital supply) pins with respect to ground (V_{SS})	—	V_{SS}–0.1	V_{SS}+0.1	V
V_{DD_BV}	SR	Voltage on VDD_BV pin (regulator supply) with respect to ground (V_{SS})	—	–0.3	6.0	V
			Relative to V_{DD}	–0.3	V_{DD}+0.3	
V_{SS_ADC}	SR	Voltage on VSS_HV_ADC (ADC reference) pin with respect to ground (V_{SS})	—	V_{SS}–0.1	V_{SS}+0.1	V
V_{DD_ADC}	SR	Voltage on VDD_HV_ADC pin (ADC reference) with respect to ground (V_{SS})	—	–0.3	6.0	V
			Relative to V_{DD}	V_{DD} –0.3	V_{DD}+0.3	
V_{IN}	SR	Voltage on any GPIO pin with respect to ground (V_{SS})	—	–0.3	6.0	V
			Relative to V_{DD}	—	V_{DD}+0.3	
I_{INJPAD}	SR	Injected input current on any pin during overload condition	—	–10	10	mA
I_{INJSUM}	SR	Absolute sum of all injected input currents during overload condition	—	–50	50	
I_{AVGSEG}	SR	Sum of all the static I/O current within a supply segment	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	70	mA
			V_{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	64	
I_{CORELV}	SR	Low voltage static current sink through VDD_BV	—	—	150	mA
$T_{STORAGE}$	SR	Storage temperature	—	–55	150	°C

NOTE

Stresses exceeding the recommended absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. During overload conditions ($V_{IN} > V_{DD}$ or $V_{IN} < V_{SS}$), the voltage on pins with respect to ground (V_{SS}) must not exceed the recommended values.

3.13 Recommended operating conditions

Table 13. Recommended operating conditions (3.3 V)

Symbol		Parameter	Conditions	Value		Unit
				Min	Max	
V_{SS}	SR	Digital ground on VSS_HV pins	—	0	0	V
V_{DD}[1]	SR	Voltage on VDD_HV pins with respect to ground (V_{SS})	—	3.0	3.6	V
V_{SS_LV}[2]	SR	Voltage on VSS_LV (low voltage digital supply) pins with respect to ground (V_{SS})	—	V_{SS}–0.1	V_{SS}+0.1	V
V_{DD_BV}[3]	SR	Voltage on VDD_BV pin (regulator supply) with respect to ground (V_{SS})	—	3.0	3.6	V
			Relative to V_{DD}	V_{DD}–0.1	V_{DD}+0.1	
V_{SS_ADC}	SR	Voltage on VSS_HV_ADC (ADC reference) pin with respect to ground (V_{SS})	—	V_{SS}–0.1	V_{SS}+0.1	V
V_{DD_ADC}[4]	SR	Voltage on VDD_HV_ADC pin (ADC reference) with respect to ground (V_{SS})	—	3.0[5]	3.6	V
			Relative to V_{DD}	V_{DD}–0.1	V_{DD}+0.1	
V_{IN}	SR	Voltage on any GPIO pin with respect to ground (V_{SS})	—	V_{SS}–0.1	—	V
			Relative to V_{DD}	—	V_{DD}+0.1	
I_{INJPAD}	SR	Injected input current on any pin during overload condition	—	–5	5	mA
I_{INJSUM}	SR	Absolute sum of all injected input currents during overload condition	—	–50	50	
TV_{DD}	SR	V_{DD} slope to ensure correct power up[6]	—	—	0.25	V/µs
$T_{A\ C\text{-}Grade\ Part}$	SR	Ambient temperature under bias	$f_{CPU} \leq 64$ MHz	–40	85	°C
$T_{J\ C\text{-}Grade\ Part}$	SR	Junction temperature under bias		–40	110	
$T_{A\ V\text{-}Grade\ Part}$	SR	Ambient temperature under bias		–40	105	
$T_{J\ V\text{-}Grade\ Part}$	SR	Junction temperature under bias		–40	130	
$T_{A\ M\text{-}Grade\ Part}$	SR	Ambient temperature under bias		–40	125	
$T_{J\ M\text{-}Grade\ Part}$	SR	Junction temperature under bias		–40	150	

1 100 nF capacitance needs to be provided between each V_{DD}/V_{SS} pair

2 330 nF capacitance needs to be provided between each V_{DD_LV}/V_{SS_LV} supply pair.

3 400 nF capacitance needs to be provided between V_{DD_BV} and the nearest V_{SS_LV} (higher value may be needed depending on external regulator characteristics).

4 100 nF capacitance needs to be provided between V_{DD_ADC}/V_{SS_ADC} pair.

5 Full electrical specification cannot be guaranteed when voltage drops below 3.0 V. In particular, ADC electrical characteristics and I/Os DC electrical specification may not be guaranteed. When voltage drops below V_{LVDHVL}, device is reset.

6 Guaranteed by device validation

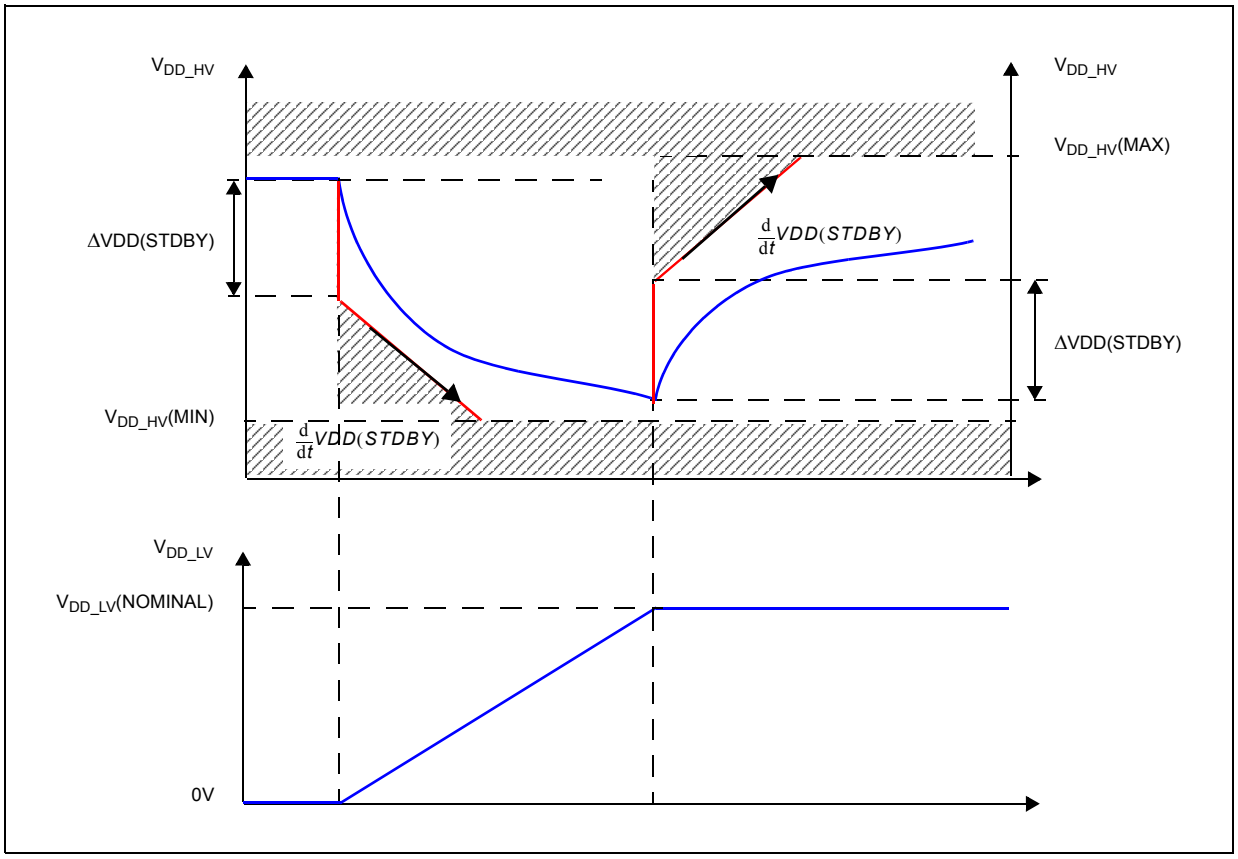

Figure 12. V_{DD_HV} and V_{DD_BV} supply constraints during STANDBY mode exit

Table 26. Voltage regulator electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
C_{REGn}	SR	—	Internal voltage regulator external capacitance	—	200	—	500	nF
R_{REG}	SR	—	Stability capacitor equivalent serial resistance	Range: 10 kHz to 20 MHz	—	—	0.2	Ω
C_{DEC1}	SR	—	Decoupling capacitance[2] ballast	V_{DD_BV}/V_{SS_LV} pair: V_{DD_BV} = 4.5 V to 5.5 V	100[3]	470[4]	—	nF
				V_{DD_BV}/V_{SS_LV} pair: V_{DD_BV} = 3 V to 3.6 V	400		—	
C_{DEC2}	SR	—	Decoupling capacitance regulator supply	V_{DD}/V_{SS} pair	10	100	—	nF
$\left\|\frac{d}{dt}VDD\right\|$	SR	—	Maximum slope on V_{DD}		—	—	250	mV/µs
$\|\Delta_{VDD(STDBY)}\|$	SR	—	Maximum instant variation on V_{DD} during standby exit		—	—	30	mV

2 This is the recommended range of load capacitance at OSC32K_XTAL and OSC32K_EXTAL with respect to ground. It includes all the parasitics due to board traces, crystal and package.

3 Maximum ESR (R_m) of the crystal is 50 kΩ

4 C0 includes a parasitic capacitance of 2.0 pF between OSC32K_XTAL and OSC32K_EXTAL pins

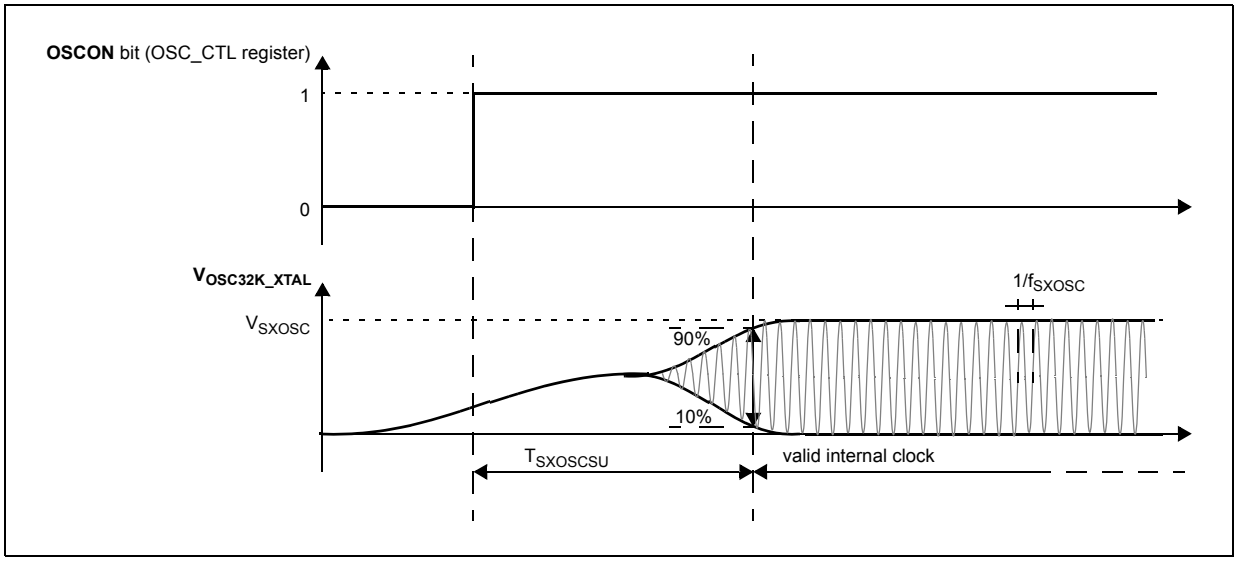

Figure 18. Slow external crystal oscillator (32 kHz) timing diagram

Table 40. Slow external crystal oscillator (32 kHz) electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
f_{SXOSC}	SR	—	Slow external crystal oscillator frequency	—	32	32.768	40	kHz
V_{SXOSC}	CC	T	Oscillation amplitude	—	—	2.1	—	V
$I_{SXOSCBIAS}$	CC	T	Oscillation bias current	—	—	2.5	—	µA
I_{SXOSC}	CC	T	Slow external crystal oscillator consumption	—	—	—	8	µA
$T_{SXOSCSU}$	CC	T	Slow external crystal oscillator start-up time	—	—	—	2[2]	s

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified. Values are specified for no neighbor GPIO pin activity. If oscillator is enabled (OSC32K_XTAL and OSC32K_EXTAL pins), neighboring pins should not toggle.

2 Start-up time has been measured with EPSON TOYOCOM MC306 crystal. Variation may be seen with other crystal.

3.23 FMPLL electrical characteristics

The device provides a frequency-modulated phase-locked loop (FMPLL) module to generate a fast system clock from the main oscillator driver.

possible, ideally infinite. This capacitor contributes to attenuating the noise present on the input pin; furthermore, it sources charge during the sampling phase, when the analog signal source is a high-impedance source.

A real filter can typically be obtained by using a series resistance with a capacitor on the input pin (simple RC filter). The RC filtering may be limited according to the value of source impedance of the transducer or circuit supplying the analog signal to be measured. The filter at the input pins must be designed taking into account the dynamic characteristics of the input signal (bandwidth) and the equivalent input impedance of the ADC itself.

In fact a current sink contributor is represented by the charge sharing effects with the sampling capacitance: being C_S and C_{p2} substantially two switched capacitances, with a frequency equal to the conversion rate of the ADC, it can be seen as a resistive path to ground. For instance, assuming a conversion rate of 1 MHz, with C_S+C_{p2} equal to 3 pF, a resistance of 330 kΩ is obtained ($R_{EQ} = 1 / (f_c \times (C_S+C_{p2}))$, where f_c represents the conversion rate at the considered channel). To minimize the error induced by the voltage partitioning between this resistance (sampled voltage on C_S+C_{p2}) and the sum of $R_S + R_F$, the external circuit must be designed to respect the Equation 4:

Eqn. 4

$$V_A \bullet \frac{R_S + R_F}{R_{EQ}} < \frac{1}{2} LSB$$

Equation 4 generates a constraint for external network design, in particular on a resistive path.

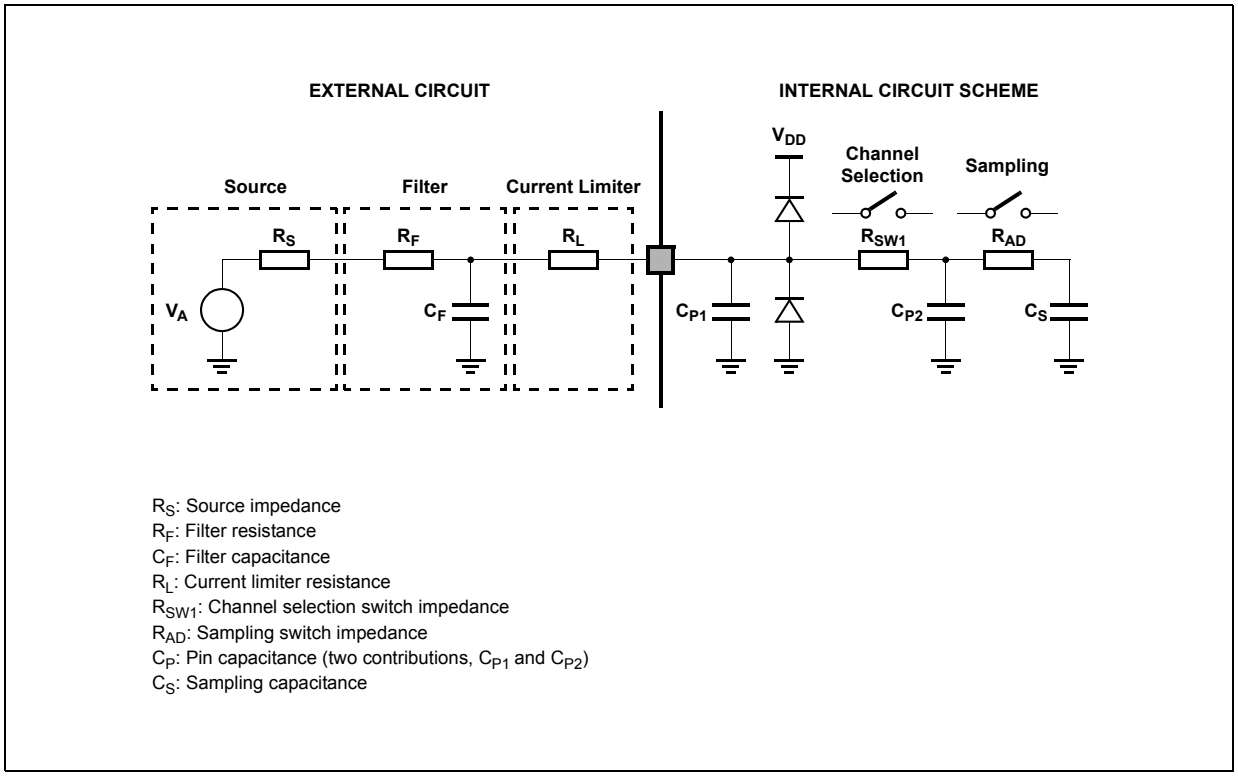

Figure 20. Input equivalent circuit (precise channels)

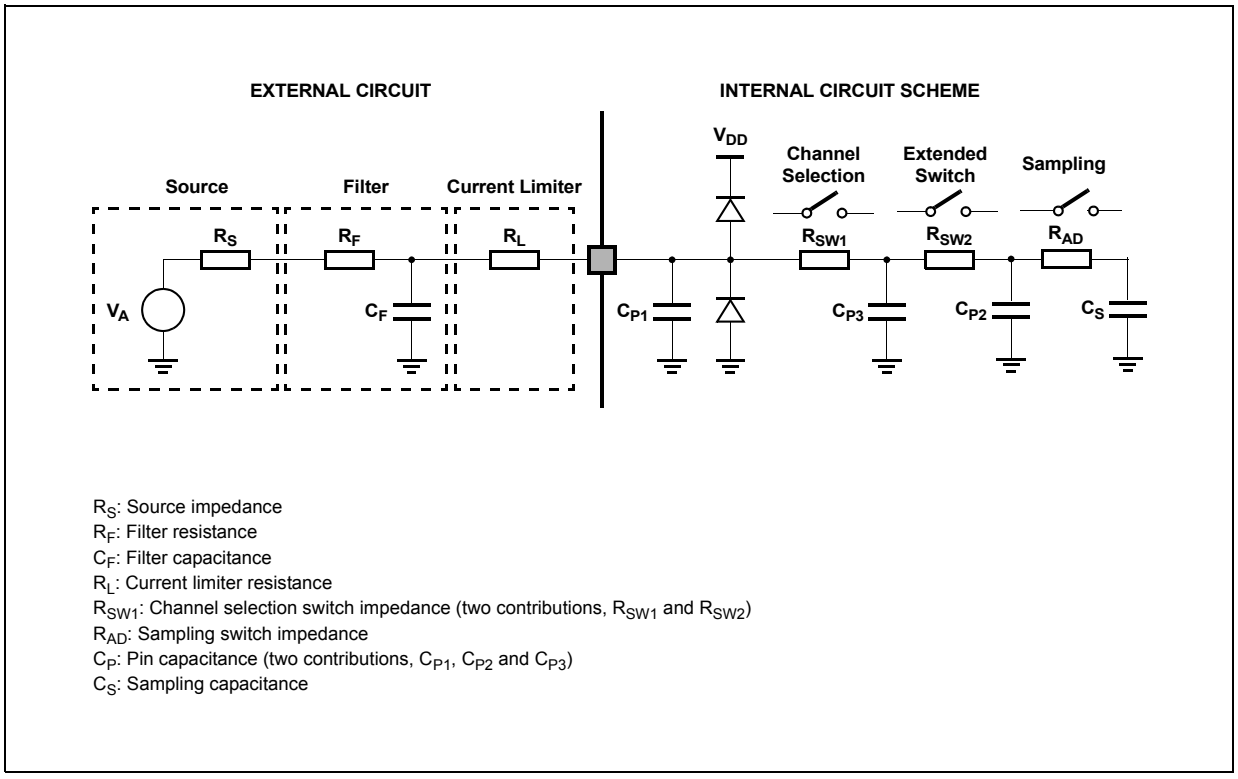

Figure 21. Input equivalent circuit (extended channels)

A second aspect involving the capacitance network shall be considered. Assuming the three capacitances C_F, C_{P1} and C_{P2} are initially charged at the source voltage V_A (refer to the equivalent circuit in Figure 20): A charge sharing phenomenon is installed when the sampling phase is started (A/D switch close).

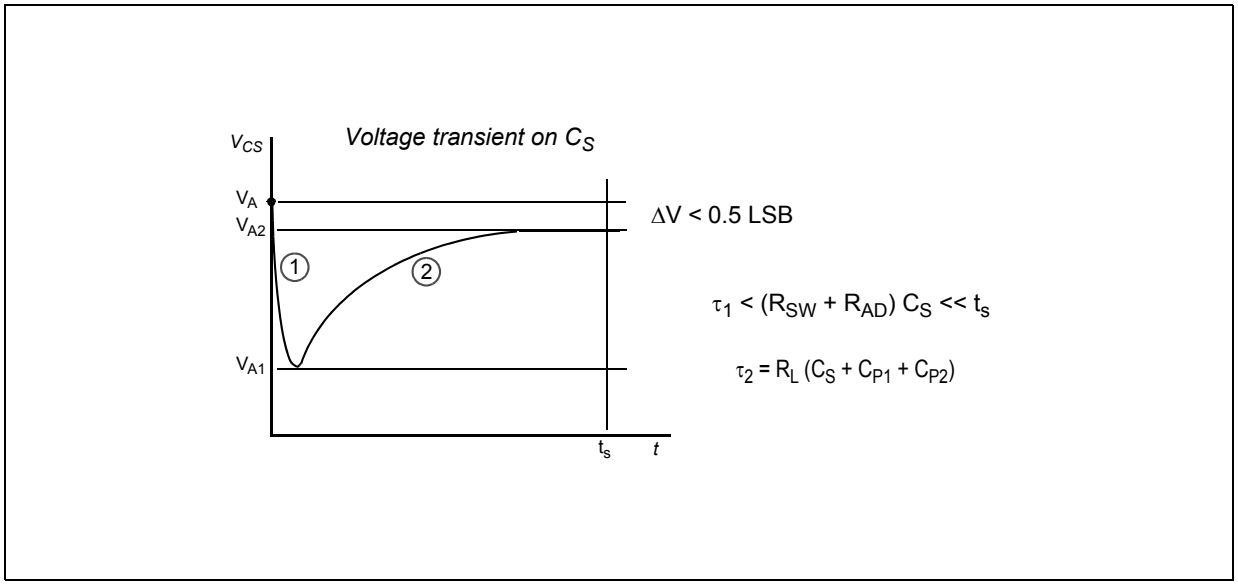

Figure 22. Transient behavior during sampling phase

In particular two different transient periods can be distinguished:

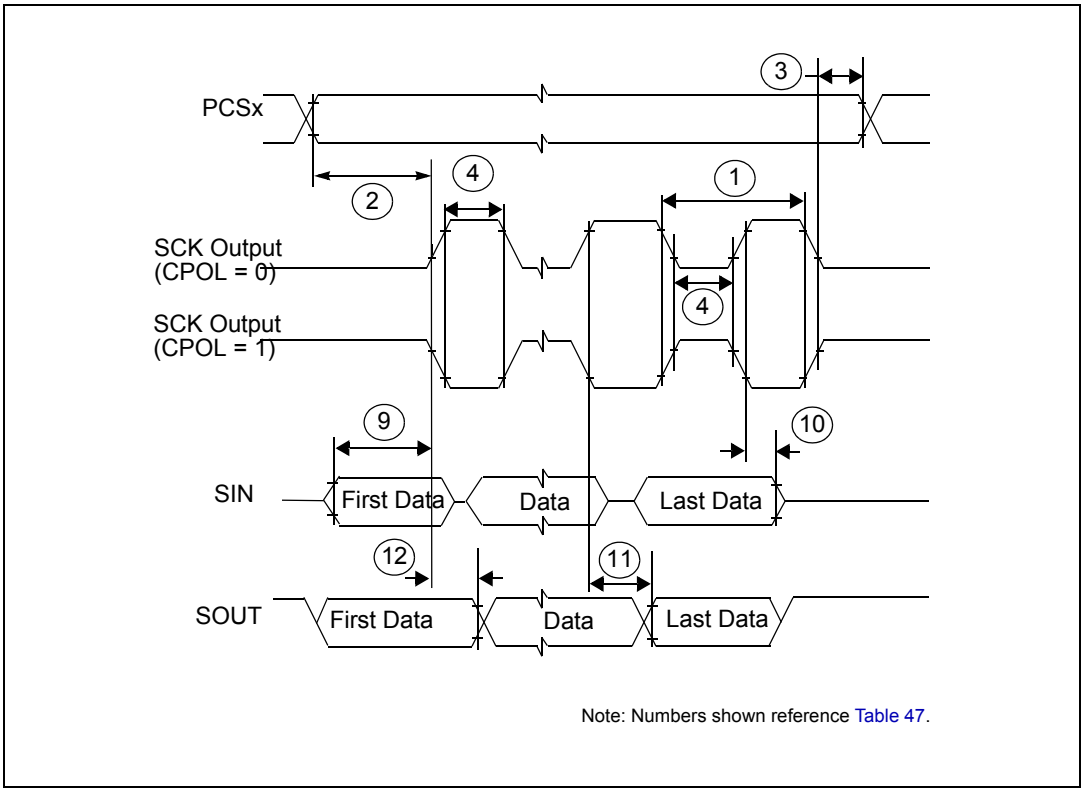

Figure 28. DSPI modified transfer format timing – master, CPHA = 0

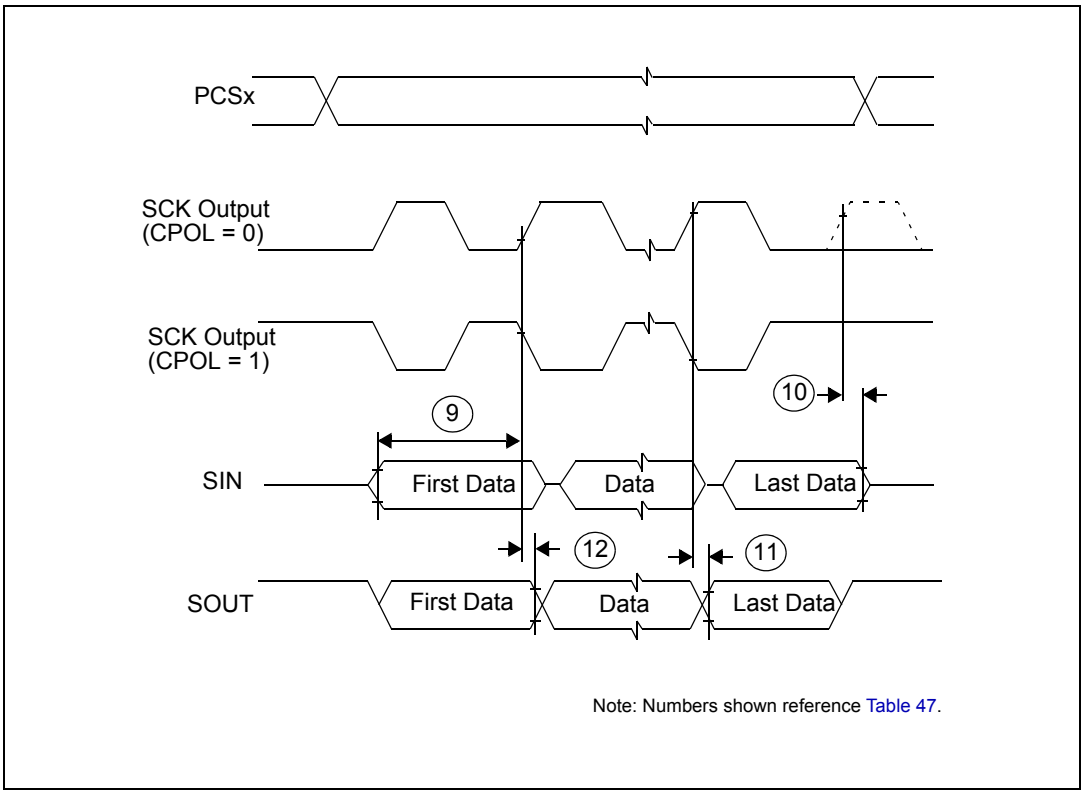

Figure 29. DSPI modified transfer format timing – master, CPHA = 1

4.1.3 144 LQFP

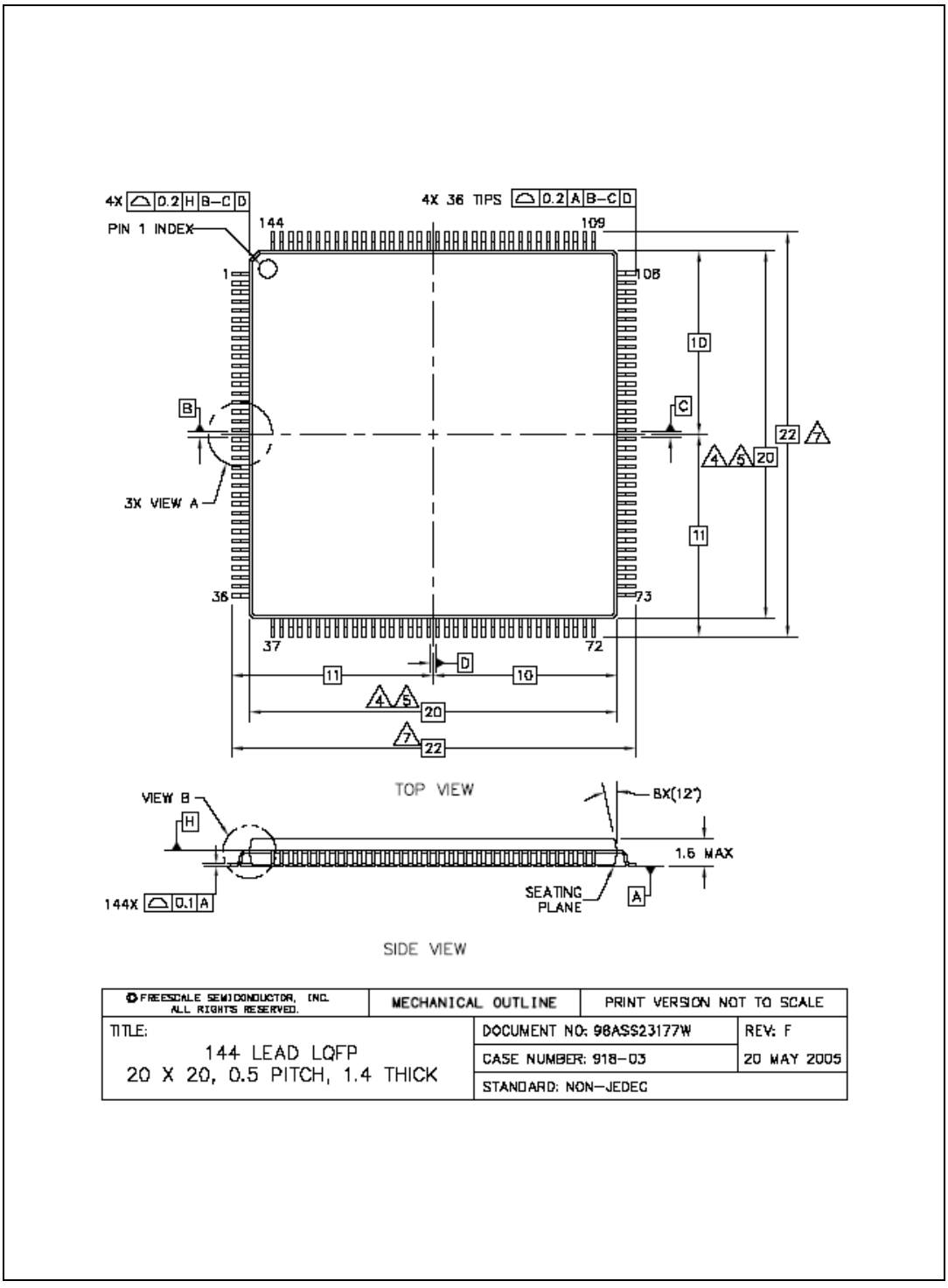

Figure 41. 144 LQFP package mechanical drawing (1 of 2)

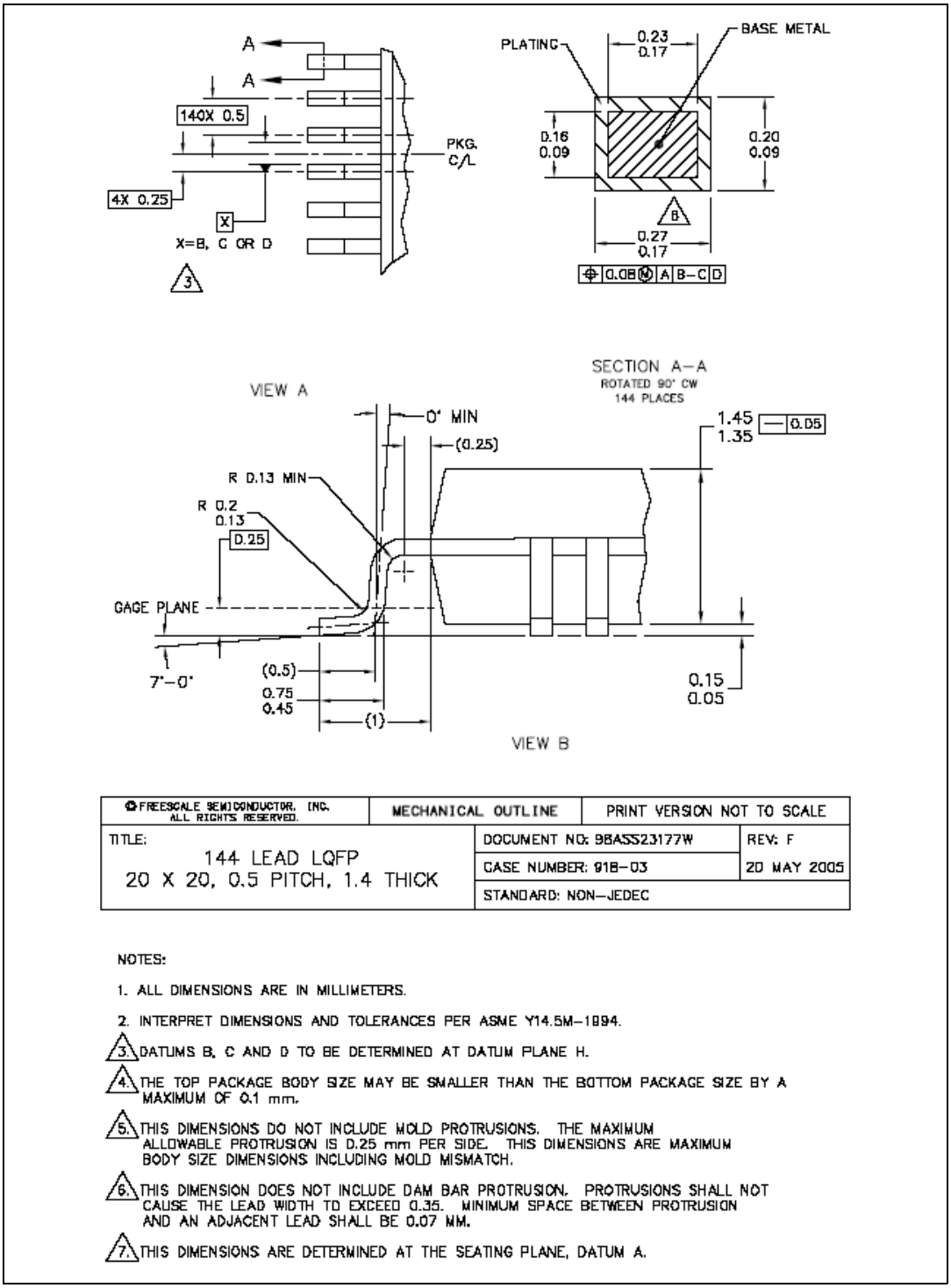

Figure 42. 144 LQFP package mechanical drawing (2 of 2)

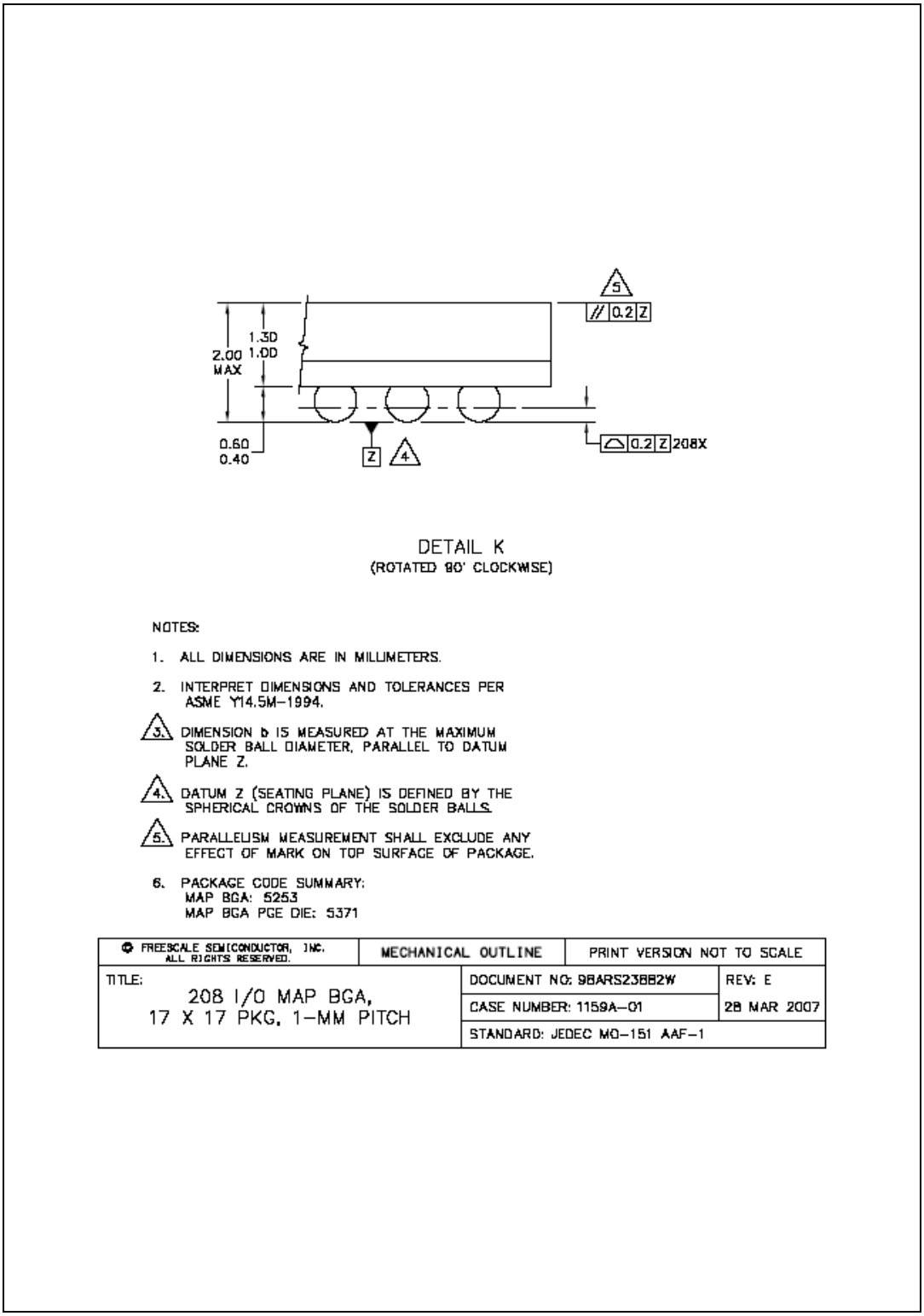

Figure 44. 208 MAPBGA package mechanical drawing (2 of 2)

Table 50. Revision history (continued)

Revision	Date	Description of Changes
10	15 Oct 2012	Table 1 (MPC5604B/C device comparison), added footnote for MPC5603BxLH and MPC5604BxLH about FlexCAN availability. Table 3 (MPC5604B/C series block summary), replaced “System watchdog timer” with “Software watchdog timer” and specified AUTOSAR (Automotive Open System Architecture) Table 6 (Functional port pin descriptions): replaced footnote “Available only on MPC560xC versions and MPC5604B 208 MAPBGA devices” with “Available only on MPC560xC versions, MPC5603B 64 LQFP, MPC5604B 64 LQFP and MPC5604B 208 MAPBGA devices”, replaced VDD with VDD_HV Figure 10 (Voltage regulator capacitance connection), updated pin name apperence Renamed Figure 11 (V_{DD_HV} and V_{DD_BV} maximum slope) (was “VDD and VDD_BV maximum slope”) Renamed Figure 12 (V_{DD_HV} and V_{DD_BV} supply constraints during STANDBY mode exit) (was “VDD and VDD_BV supply constraints during STANDBY mode exit”) Table 13 (Recommended operating conditions (3.3 V)), added minimum value of T_{VDD} and footnote about it. Table 14 (Recommended operating conditions (5.0 V)), added minimum value of T_{VDD} and footnote about it. Section 3.17.1, “Voltage regulator electrical characteristics: replaced “slew rate of V_{DD}/V_{DD_BV}” with “slew rate of both V_{DD_HV} and V_{DD_BV}” replaced “When STANDBY mode is used, further constraints apply to the V_{DD}/V_{DD_BV} in order to guarantee correct regulator functionality during STANDBY exit.” with “When STANDBY mode is used, further constraints are applied to the both V_{DD_HV} and V_{DD_BV} in order to guarantee correct regulator function during STANDBY exit.” Table 28 (Power consumption on VDD_BV and VDD_HV), updated footnotes of I_{DDMAX} and I_{DDRUN} stating that both currents are drawn only from the V_{DD_BV} pin. Table 32 (Flash memory power supply DC electrical characteristics), in the paremeter column replaced V_{DD_BV} and V_{DD_HV} respectively with VDD_BV and VDD_HV. Table 46 (On-chip peripherals current consumption), in the paremeter column replaced V_{DD_BV}, V_{DD_HV} and $V_{DD\_HV\_ADC}$ respectively with VDD_BV, VDD_HV and VDD_HV_ADC Updated Section 3.26.2, “Input impedance and ADC accuracy Table 47 (DSPI characteristics), modified symbol for t_{PCSC} and t_{PASC}
11	14 Nov 2012	In the cover feature list: added “and ECC” at the end of “Up to 512 KB on-chip code flash supported with the flash controller” added “with ECC” at the end of “Up to 48 KB on-chip SRAM” Table 13 (Recommended operating conditions (3.3 V)), removed minimum value of T_{VDD} and relative footnote. Table 14 (Recommended operating conditions (5.0 V)), removed minimum value of T_{VDD} and relative footnote.

Appendix A Abbreviations

Table A-1 lists abbreviations used but not defined elsewhere in this document.

Table A-1. Abbreviations

Abbreviation	Meaning
CMOS	Complementary metal–oxide–semiconductor
CPHA	Clock phase
CPOL	Clock polarity
CS	Peripheral chip select
EVTO	Event out
MCKO	Message clock out
MDO	Message data out
MSEO	Message start/end out
MTFE	Modified timing format enable
SCK	Serial communications clock
SOUT	Serial data out
TBD	To be defined
TCK	Test clock input
TDI	Test data input
TDO	Test data output
TMS	Test mode select

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